NSN 5962-01-352-1002

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-352-1002

Overall Height:
0.400 inches
Body Length:
1.060 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.130 inches and 0.185 inches
Maximum Power Dissipation Rating:
900.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Radar set an/sps-4 (v) 7
Features Provided:
Hermetically sealed and burn in and monolithic and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Output Logic Form: Transistor-transistor logic
Transistor-transistor logic
Transistor-transistor logic Input Circuit Pattern:
Transistor-transistor logic Input Circuit Pattern: 8 input
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator:
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic:
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic: 165.00 milliamperes reverse current, dc absolute
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic: 165.00 milliamperes reverse current, dc absolute Terminal Surface Treatment:
Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic: 165.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic: 165.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic:
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic: 165.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic: 165.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source Time Rating Per Chacteristic:
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic: 165.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source Time Rating Per Chacteristic: 40.00 nanoseconds delay
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic: 165.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source Time Rating Per Chacteristic: 40.00 nanoseconds delay Memory Device Type:
Transistor-transistor logic Input Circuit Pattern: 8 input Case Outline Source And Designator: D-8 mil-m-38510 Current Rating Per Characteristic: 165.00 milliamperes reverse current, dc absolute Terminal Surface Treatment: Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source Time Rating Per Chacteristic: 40.00 nanoseconds delay Memory Device Type: Pal

20 printed circuit

NSN 5962-01-352-1002

Memory Microcircuit - Page 2 of 2



_					
٠.	h	_	I+	18	e:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0